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April 1<sup>st</sup>, 2010 Renesas Electronics Corporation

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## MOS FIELD EFFECT TRANSISTOR 2SK3115

### SWITCHING N-CHANNEL POWER MOS FET INDUSTRIAL USE

### **DESCRIPTION**

The 2SK3115 is N-Channel DMOS FET device that features a low gate charge and excellent switching haracteristics, and designed for high voltage applications such as switching power supply, AC adapter.

### **FEATURES**

- Low gate charge
   QG = 26 nC TYP. (VDD = 450 V, VGS = 10 V, ID = 6.0 A)
- Gate voltage rating ±30 V
- Low on-state resistance RDS(on) = 1.2  $\Omega$  MAX. (Vgs = 10 V, ID = 3.0 A)
- · Avalanche capability ratings

### ORDERING INFORMATION

PART NUMBER	PACKAGE
2SK3115	Isolated TO-220

(Isolated TO-220)



### ABSOLUTE MAXIMUM RATINGS (TA = 25°C)

Drain to Source Voltage (Ves = 0 V)	VDSS	600	V
Gate to Source Voltage (Vps = 0 V)	Vgss	±30	V
Drain Current (DC) (Tc = 25°C)	ID(DC)	±6.0	Α
Drain Current (pulse) Note1	D(pulse)	±24	Α
Total Power Dissipation (TA = 25°C)	P <sub>T1</sub>	2.0	W
Total Power Dissipation (Tc = 25°C)	P <sub>T2</sub>	35	W
Channel Temperature	Tch	150	°C
Storage Temperature	Tstg	-55 to +150	°C
Single Avalanche Current Note2	IAS	6.0	Α
Single Avalanche Energy Note2	Eas	24	mJ

**Notes 1.** PW  $\leq$  10  $\mu$ s, Duty Cycle  $\leq$  1%

**2.** Starting  $T_{ch} = 25^{\circ}C$ ,  $V_{DD} = 150 \text{ V}$ ,  $R_{G} = 25 \Omega$ ,  $V_{GS} = 20 \rightarrow 0 \text{ V}$ 

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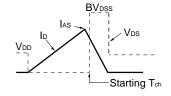


### **ELECTRICAL CHARACTERISTICS (TA = 25°C)**

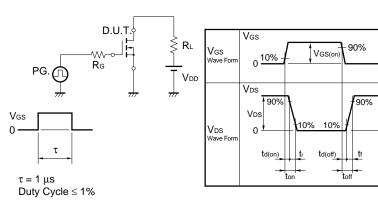
Characteristics	Symbol	Test Conditions	MIN.	TYP.	MAX.	Unit
Zero Gate Voltage Drain Current	Ioss	V <sub>DS</sub> = 600 V, V <sub>GS</sub> = 0 V			100	μΑ
Gate Leakage Current	Igss	VGS = ±30 V, VDS = 0 V			±100	nA
Gate Cut-off Voltage	V <sub>GS(off)</sub>	V <sub>DS</sub> = 10 V, I <sub>D</sub> = 1 mA	2.5		3.5	V
Forward Transfer Admittance	yfs	V <sub>DS</sub> = 10 V, I <sub>D</sub> = 3.0 A	2.0			S
Drain to Source On-state Resistance	RDS(on)	Vgs = 10 V, ID = 3.0 A		0.9	1.2	Ω
Input Capacitance	Ciss	V <sub>DS</sub> = 10 V		1100		pF
Output Capacitance	Coss	Vgs = 0 V		200		pF
Reverse Transfer Capacitance	Crss	f = 1 MHz		20		pF
Turn-on Delay Time	td(on)	V <sub>DD</sub> = 150 V, I <sub>D</sub> = 3.0 A		18		ns
Rise Time	<b>t</b> r	V <sub>GS(on)</sub> = 10 V		12		ns
Turn-off Delay Time	t <sub>d(off)</sub>	$R_G = 10 \Omega$ , $R_L = 50 \Omega$		50		ns
Fall Time	tr			15		ns
Total Gate Charge	Q <sub>G</sub>	V <sub>DD</sub> = 450 V		26		nC
Gate to Source Charge	Qgs	Vgs = 10 V		6		nC
Gate to Drain Charge	Q <sub>GD</sub>	ID = 6.0 A		10		nC
Body Diode Forward Voltage	V <sub>F(S-D)</sub>	IF = 6.0 A, VGS = 0 V		1.0		V
Reverse Recovery Time	trr	IF = 6.0 A, VGS = 0 V		1.4		μs
Reverse Recovery Charge	Qrr	di/dt = 50 A/μs		6.5		μC

### \* TEST CIRCUIT 1 AVALANCHE CAPABILITY

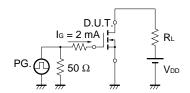
## $\begin{array}{c} \text{D.U.T.} \\ \text{RG} = 25 \ \Omega \\ \text{VGS} = 20 \rightarrow 0 \ \text{V} \end{array} \begin{array}{c} \text{PG.} \\ \text{PS.} \\ \text{PS.} \\ \text{M.S.} \end{array} \begin{array}{c} \text{D.U.T.} \\ \text{I.I.} \\ \text{VDD} \\ \text{M.S.} \end{array}$



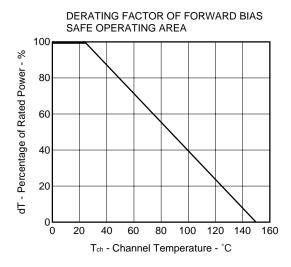
### **TEST CIRCUIT 2 SWITCHING TIME**

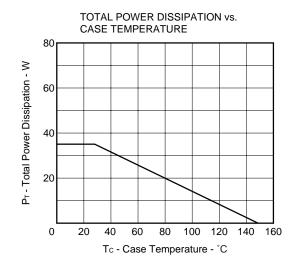


### **TEST CIRCUIT 3 GATE CHARGE**



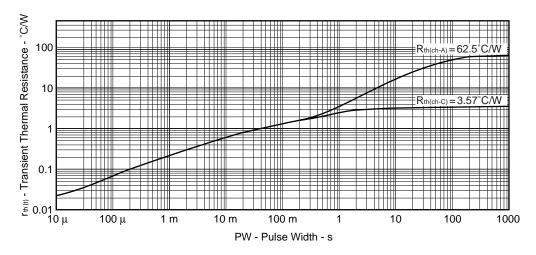
### **★ TYPICAL CHARACTERISTICS (TA = 25°C)**





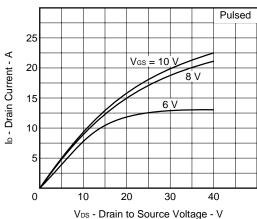
# FORWARD BIAS SAFE OPERATING AREA 100 10 | Dipulse) 10 | Tc = 25°C | Single Pulse 0.1 | 10 | 100 | 1000 Vos - Drain to Source Voltage - V

### TRANSIENT THERMAL RESISTANCE vs. PULSE WIDTH

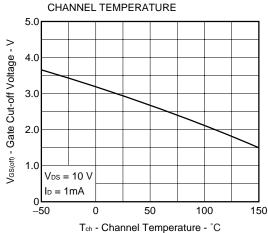


3

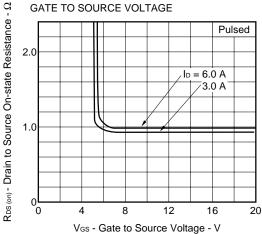
### DRAIN CURRENT vs. DRAIN TO SOURCE VOLTAGE



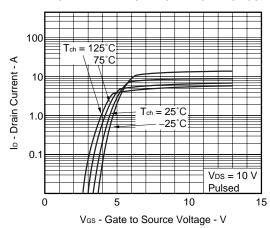
### GATE CUT-OFF VOLTAGE vs.



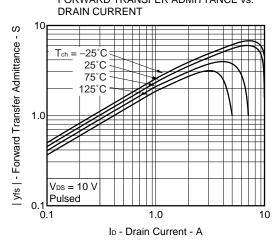
### DRAIN TO SOURCE ON-STATE RESISTANCE vs. GATE TO SOURCE VOLTAGE



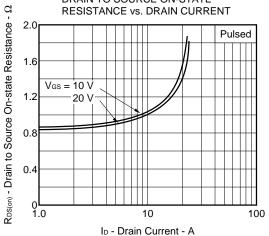
### FORWARD TRANSFER CHARACTERISTICS



### FORWARD TRANSFER ADMITTANCE vs.

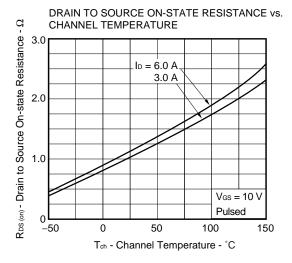


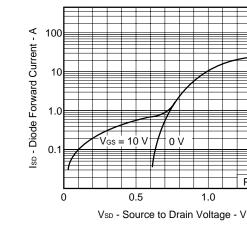
### DRAIN TO SOURCE ON-STATE

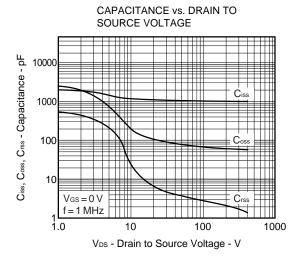


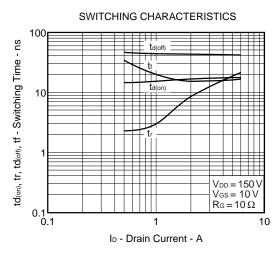
Pulsed

1.5

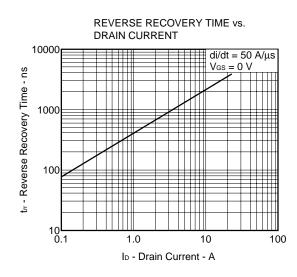


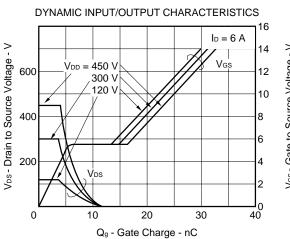




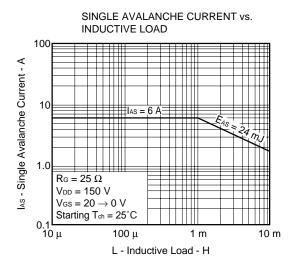


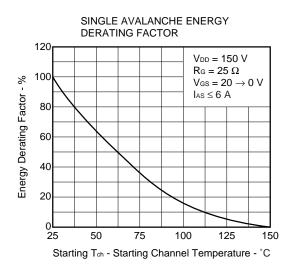
SOURCE TO DRAIN DIODE FORWARD VOLTAGE





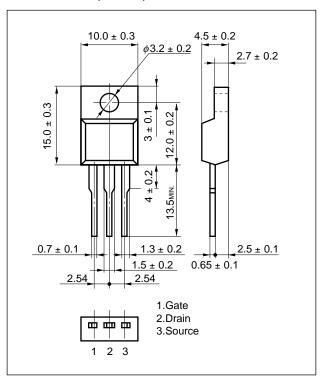
Ves - Gate to Source Voltage - V



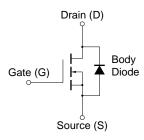


### **PACKAGE DRAWING (Unit: mm)**

### Isolated TO-220(MP-45F)



### **EQUIVALENT CIRCUIT**



**Remark** Strong electric field, when exposed to this device, can cause destruction of the gate oxide and ultimately degrade the device operation. Steps must be taken to stop generation of static electricity as much as possible, and quickly dissipate it once, when it has occurred.

**NEC** 2SK3115

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